

### 60V P-Channel Enhancement Mode MOSFET

Current

#### Features

Voltage

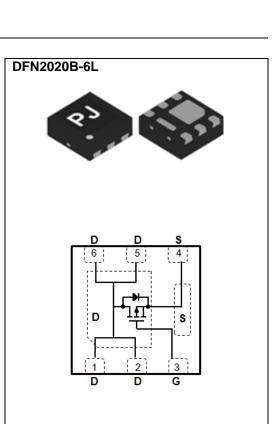
- $R_{DS(ON)}$ ,  $V_{GS}$ @-10V,  $I_D$ @-2A<190m $\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}$ @-4.5V,  $I_D$ @-1.5A<240m $\Omega$

-60 V

- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case : DFN2020B-6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0086 grams



#### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25<sup>o</sup>C unless otherwise noted)

-2.4 A

PARAMETER	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V <sub>DS</sub>	-60	V	
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 20		
Continuous Drain Current (Note 4)	T <sub>A</sub> =25°C		-2.4		
	T <sub>A</sub> =70°C	ID	-1.9	А	
Pulsed Drain Current (Note 1)	Ідм	-9.6			
	T <sub>A</sub> =25°C	_	2	W	
Power Dissipation	T <sub>A</sub> =70°C	PD PD	1.3		
Single Pulse Avalanche Energy (Note 6)	Eas	32	mJ		
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	٥C	
Typical Thermal Resistance - Junction to Ambient <sup>(Note 4,5)</sup>		Reja	62.5	°C/W	



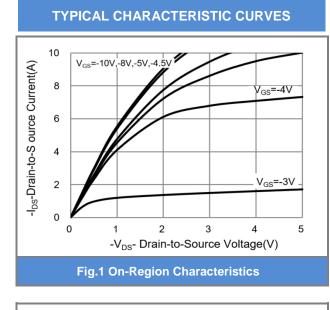
#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

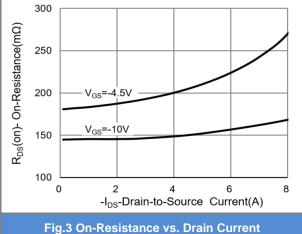
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	BV <sub>DSS</sub> V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-60	-	-	- V 2.5
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-1.0	-1.88	-2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-2A	-	140	190	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-1.5A	-	190	240	
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-60V, V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	lgss	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	$\mathbf{Q}_{g}$	V <sub>DS</sub> =-30V, I <sub>D</sub> =-2A, V <sub>GS</sub> =-10V <sup>(Note 1,2)</sup>	-	8.3	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	1.8	-	
Gate-Drain Charge	$Q_{gd}$		-	1.6	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V, f=1MHZ	-	430	-	pF
Output Capacitance	Coss		-	33	-	
Reverse Transfer Capacitance	Crss		-	29	-	
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =-30V, I <sub>D</sub> =-1A, V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω <sup>(Note 1,2)</sup>	-	5.1	-	
Turn-On Rise Time	tr		-	20	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	36	-	
Turn-Off Fall Time	tf		-	11	-	
Drain-Source Diode				•		
Maximum Continuous Drain-Source	ls		_	-	-1.5	А
Diode Forward Current	IS		-	-	-1.5	
Diode Forward Voltage	V <sub>SD</sub>	Is=-1A, V <sub>GS</sub> =0V	-	-0.78	-1	V

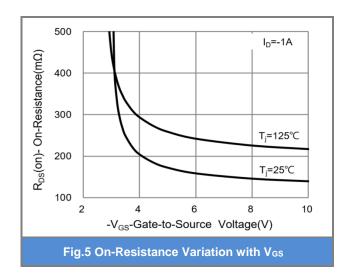
NOTES :

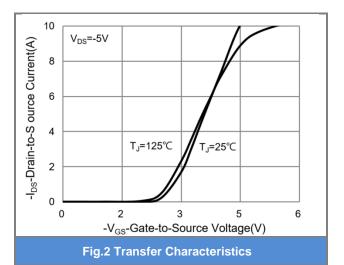
- 1. Pulse width  $\leq$  300 us, Duty cycle  $\leq$  2%.
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- R<sub>⊕JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. The test condition is L=1mH, I\_{AS}=-8A, V\_{DD}=-25V, V\_{GS}=-10V
- 7. Guaranteed by design, not subject to production testing.











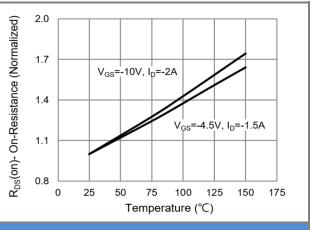
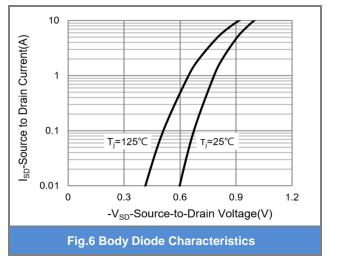
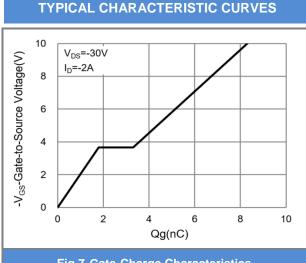


Fig.4 On-Resistance vs. Junction temperature









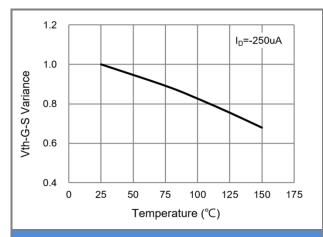
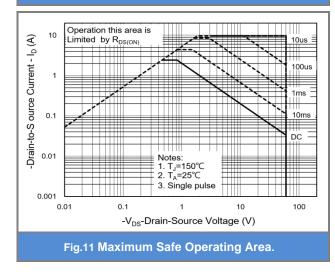
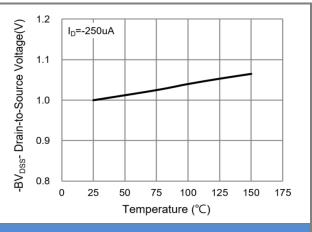


Fig.9 Threshold Voltage Variation with Temperature







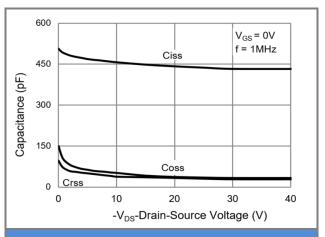
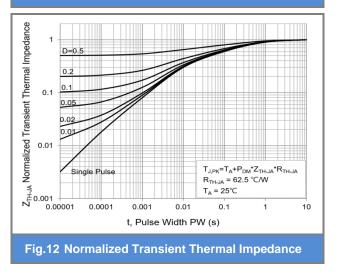


Fig.10 Capacitance vs. Drain-Source Voltage

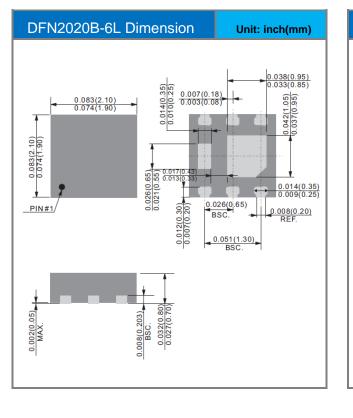


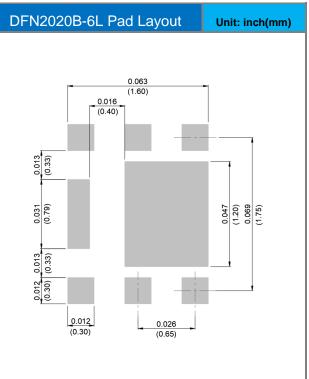


### Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ2461_R1_00001	DFN2020B-6L	3K pcs / 7" reel	461	Halogen free RoHS compliant

### Packaging Information & Mounting Pad Layout







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